Low-power 2-input NAND gate Rev. 7 — 23 April 2019

**Product data sheet** 

### 1. General description

The 74AUP1G00 provides the single 2-input NAND function.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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# 3. Ordering information

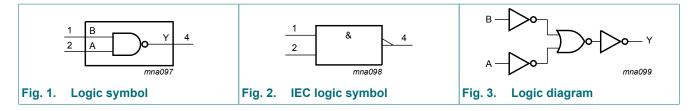
Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G00GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1G00GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886				
74AUP1G00GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891				
74AUP1G00GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115				
74AUP1G00GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				
74AUP1G00GX	-40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.35 mm	SOT1226				

### 4. Marking

Table 2. Marking	
Type number	Marking code [1]
74AUP1G00GW	pA
74AUP1G00GM	pA
74AUP1G00GF	рА
74AUP1G00GN	pA
74AUP1G00GS	pA
74AUP1G00GX	рА

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

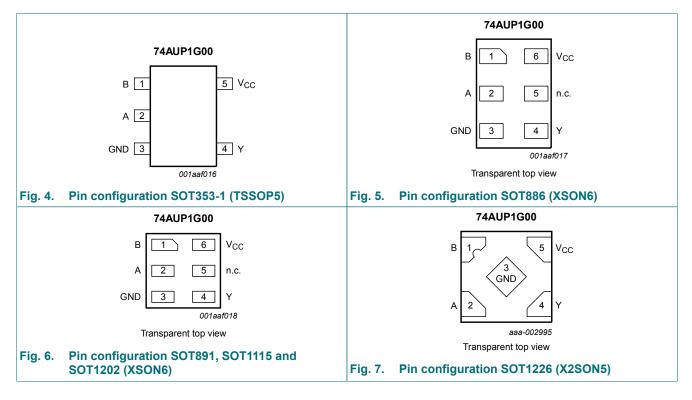
# 5. Functional diagram



74AUP1G00

### 6. Pinning information





### 6.2. Pin description

Symbol	Pin	Pin		
	TSSOP5 and X2SON5	XSON6		
В	1	1	data input	
A	2	2	data input	
GND	3	3	ground (0 V)	
Y	4	4	data output	
n.c.	-	5	not connected	
V <sub>CC</sub>	5	6	supply voltage	

### Table 3. Pin description

### 7. Functional description

#### Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input C		Output
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
Vo	output voltage	Active mode	[1]	-0.5	V <sub>CC</sub> + 0.5	V
		Power-down mode	[1]	-0.5	+4.6	V
I <sub>O</sub>	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±20	mA
I <sub>CC</sub>	supply current			-	+50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb}$ = -40 °C to +125 °C	[2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP5 packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

For XSON6 and X2SON5 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

### 9. Recommended operating conditions

#### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; $V_{CC}$ = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	0	200	ns/V

# **10. Static characteristics**

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C		I			
VIH	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	$I_{O}$ = -20 µA; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = 20 µA; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.1	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.2	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I <sub>CC</sub>	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_0 = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μA
CI	input capacitance	$V_{CC}$ = 0 V to 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub>	-	0.8	-	pF
Co	output capacitance	$V_0 = GND; V_{CC} = 0 V$	-	1.7	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C	· · · · · · · · · · · · · · · · · · ·	I			
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	$I_{O}$ = -20 µA; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = 20 µA; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
l <sub>l</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.5	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μA
T <sub>amb</sub> = -	40 °C to +125 °C		t			
VIH	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.75V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.70V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.25V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V

#### Low-power 2-input NAND gate

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
	voltage	$I_{O}$ = -20 µA; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = 20 µA; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
l <sub>l</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.75	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.75	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I <sub>CC</sub>	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V} $ [1]	-	-	75	μA

[1] One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND.

# **11. Dynamic characteristics**

#### Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9

Symbol	Parameter	Conditions	Min	Typ [1]	Мах	Unit
T <sub>amb</sub> = 2	5 °C; C <sub>L</sub> = 5 pF					
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [2]				
		V <sub>CC</sub> = 0.8 V	-	17.5	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.5	5.3	11.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.0	3.8	6.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.6	3.1	5.3	ns
		$V_{CC}$ = 2.3 V to 2.7 V	1.3	2.5	4.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	2.2	3.6	ns

#### Low-power 2-input NAND gate

Symbol	Parameter	Conditions	Min	Тур [1]	Мах	Unit
T <sub>amb</sub> = 2	25 °C; C <sub>L</sub> = 10 pF					_
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [2]				
		V <sub>CC</sub> = 0.8 V	-	21.0	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.4	6.1	13.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.4	4.4	7.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	3.7	6.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	3.0	4.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.3	2.8	4.3	ns
T <sub>amb</sub> = 2	25 °C; C <sub>L</sub> = 15 pF					
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [2]				
		V <sub>CC</sub> = 0.8 V	-	24.5	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.4	6.9	14.8	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.8	5.0	8.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	4.1	7.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	3.5	5.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.6	3.2	4.9	ns
T <sub>amb</sub> = 2	25 °C; C <sub>L</sub> = 30 pF	· · ·				
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [2]				
		V <sub>CC</sub> = 0.8 V	-	34.8	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.6	9.2	20.1	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	6.5	11.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	5.4	9.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.4	4.6	7.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.3	4.3	6.5	ns
T <sub>amb</sub> = 2	25 °C	· · · · · · · · · · · · · · · · · · ·				
C <sub>PD</sub>	power dissipation	$f = 1 \text{ MHz}; V_1 = \text{GND to } V_{\text{CC}}$ [3]				
	capacitance	V <sub>CC</sub> = 0.8 V	-	2.6	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.8	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.9	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.1	-	pF
		$V_{CC}$ = 2.3 V to 2.7 V	-	3.6	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.2	-	pF

[1] All typical values are measured at nominal V<sub>CC</sub>.

[1] Fin typical values are included ut information  $C_{CL}$ . [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ . [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o$  = output frequency in MHz;

 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

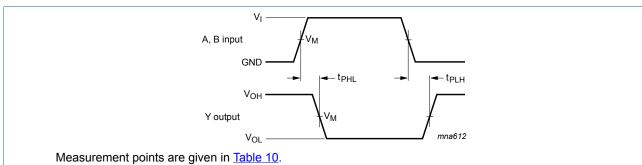
#### Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
		-	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.1	12.2	2.1	13.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.8	7.8	1.8	8.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.4	6.2	1.4	6.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.1	4.7	1.1	5.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	4.2	1.0	4.7	ns
C <sub>L</sub> = 10	pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.2	14.4	2.2	15.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	9.2	2.2	10.2	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	7.3	1.9	8.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.3	5.6	1.3	6.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.2	4.9	1.2	5.4	ns
C <sub>L</sub> = 15	pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.1	16.5	3.1	18.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.5	10.5	2.5	11.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	8.3	2.0	9.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.5	6.4	1.5	7.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.4	5.7	1.4	6.3	ns
C <sub>L</sub> = 30	pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 8</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.1	22.6	4.1	24.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.9	14.0	2.9	15.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	11.1	2.3	12.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	8.5	2.1	9.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	7.6	2.1	8.4	ns

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

### 11.1. Waveforms and test circuit

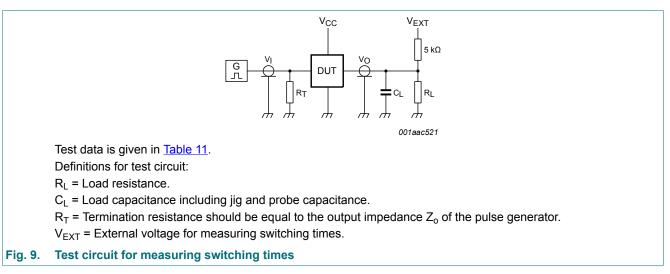


Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage drop that occur with the output load.

#### Fig. 8. The data input (A or B) to output (Y) propagation delays

### Table 10. Measurement points

Supply voltage	Input	Output		
V <sub>cc</sub>	V <sub>M</sub>	VI	$t_r = t_f$	V <sub>M</sub>
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	$0.5 \times V_{CC}$



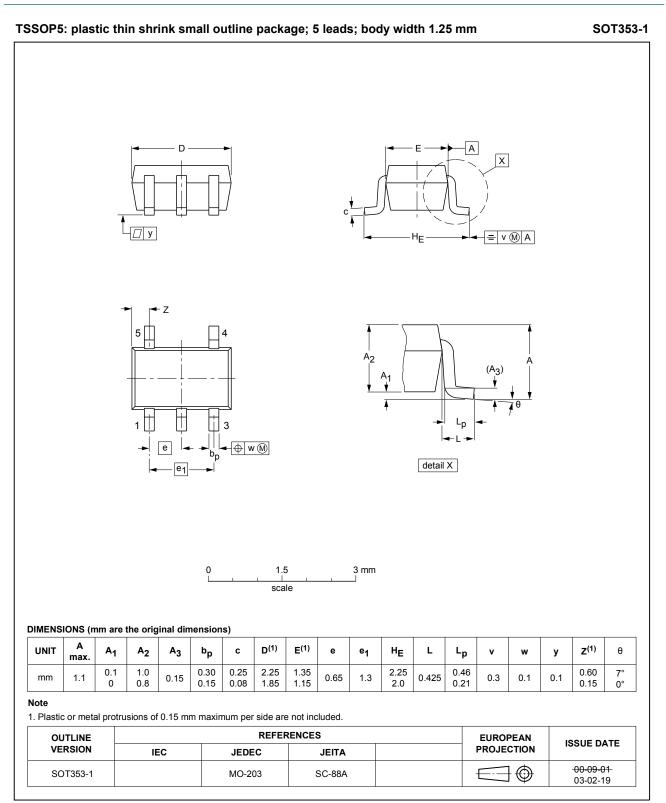
#### Table 11. Test data

Supply voltage	Load		V <sub>EXT</sub>		
V <sub>cc</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k $\Omega$ or 1 M $\Omega$	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L = 5 k\Omega$ .

For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

### 12. Package outline



#### Fig. 10. Package outline SOT353-1 (TSSOP5)

74AUP1G00

#### Low-power 2-input NAND gate

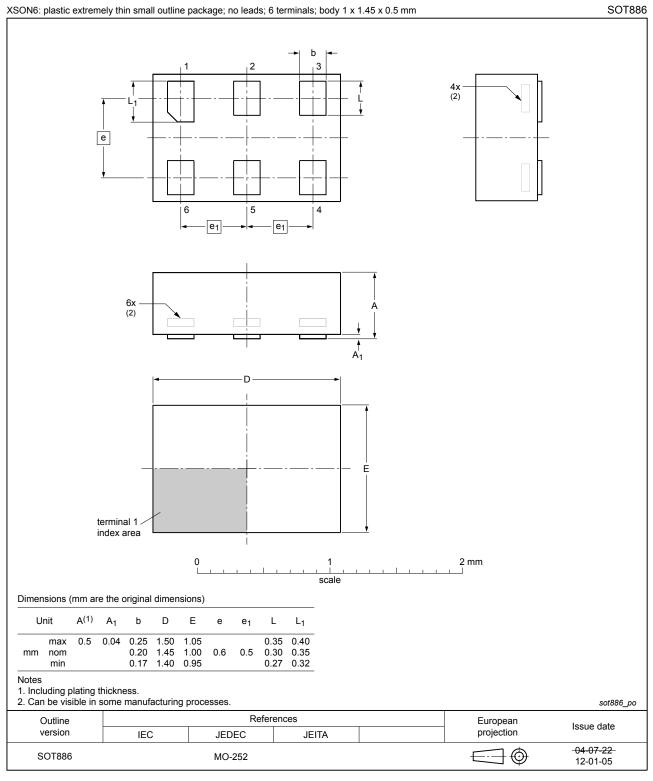


Fig. 11. Package outline SOT886 (XSON6)

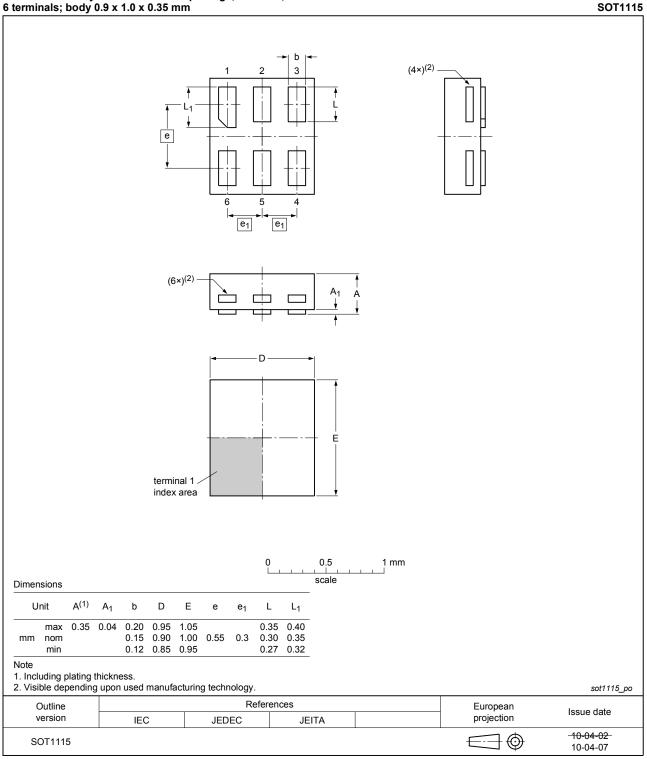
### Low-power 2-input NAND gate

SON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm						SOT							
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Fig. 12. Package outline SOT891 (XSON6)

#### Low-power 2-input NAND gate

#### XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm





#### Low-power 2-input NAND gate

#### XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

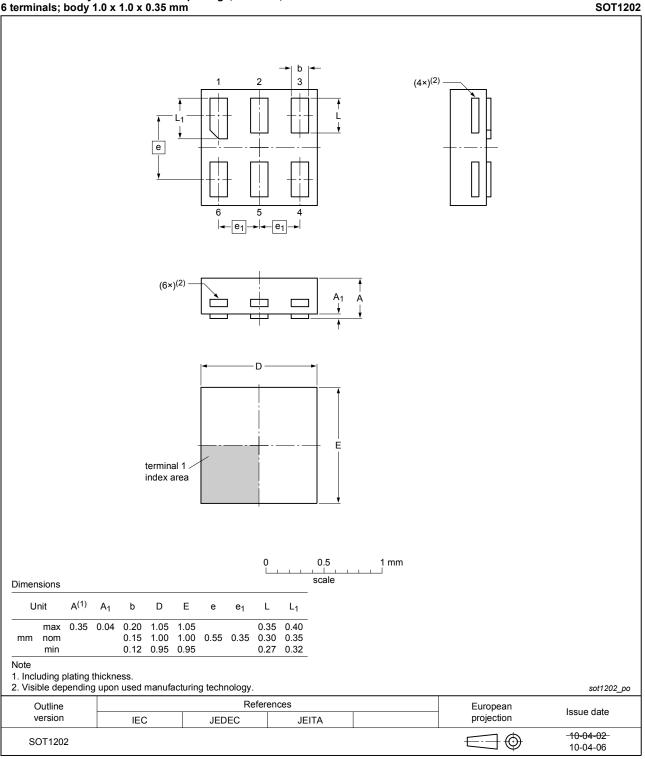
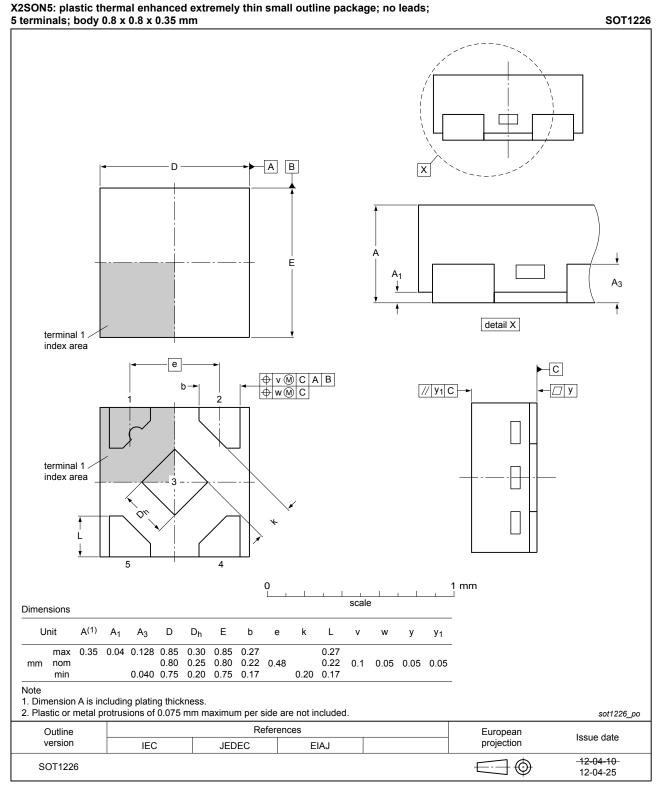


Fig. 14. Package outline SOT1202 (XSON6)

#### Low-power 2-input NAND gate





74AUP1G00

### 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 14. Revision history

#### Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74AUP1G00 v.7	20190423	Product data sheet	-	74AUP1G00 v.6				
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guideline of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Pin configuration drawing (Fig. 7) SOT1226 (X2SON5) updated.</li> </ul>							
74AUP1G00 v.6	20120627	Product data sheet	-	74AUP1G00 v.5				
Modifications:	Added type number 74AUP1G00GX (SOT1226).							
74AUP1G00 v.5	20120316	Product data sheet	-	74AUP1G00 v.4				
Modifications:	Package outline drawing of SOT886 (Fig. 11) modified.							
74AUP1G00 v.4	20111115	Product data sheet	-	74AUP1G00 v.3				
Modifications:	Legal pages updated.							
74AUP1G00 v.3	20101007	Product data sheet	-	74AUP1G00 v.2				
74AUP1G00 v.2	20060629	Product data sheet	-	74AUP1G00 v.1				
74AUP1G00 v.1	20050711	Product data sheet	-	-				

### 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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